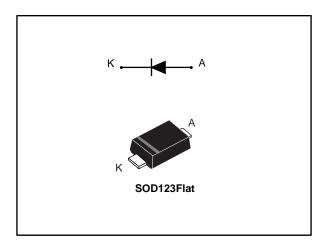


## STPS2H100ZF

## Power Schottky rectifier

Datasheet - production data



### **Description**

Single chip Schottky rectifiers suited to surface mounting and especially intended for use in high frequency converters, free-wheeling and reverse polarity protection..

**Table 1: Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	2 A
$V_{RRM}$	100 V
V <sub>F</sub> (typ.)	0.60 V
T <sub>j</sub> (max.)	175 °C

#### **Features**

- High junction temperature capability
- Low leakage current
- Negligible switching losses
- Avalanche capability specified
- ECOPACK®2 compliant component

Characteristics STPS2H100ZF

### 1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage		100	V
I <sub>F(AV)</sub>	Average forward current $ T_{L} = 140  ^{\circ}\text{C/} $ $ \delta = 0.5, \text{ square wave} $		2	Α
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		50	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 10 \mu s$ , $T_j = 125 ^{\circ}C$		105	W
T <sub>stg</sub>	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperatu	-40 to +175		

#### Notes:

**Table 3: Thermal parameters** 

Symbol	Parameter	Max. value	Unit
R <sub>th(j-l)</sub>	Junction to lead	20	°C/W

**Table 4: Static electrical characteristics** 

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
. (1)	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	$V_R = V_{RRM}$	-		1	μΑ
IR''		T <sub>j</sub> = 125 °C		-	0.2	0.5	mA
	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 2 A	-		0.86	
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 125 °C		-	0.65	0.70	\ /
VF(2)		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 4 A	-		0.96	V
		T <sub>j</sub> = 125 °C		-	0.75	0.83	

#### Notes:

 $^{(1)}$ Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2%

To evaluate the conduction losses, use the following equation:

$$P = 0.57 \times I_{F(AV)} + 0.065 \times I_{F^{2}(RMS)}$$

For more information, please refer to the following application notes related to the power losses.

- AN604 (Calculation of conduction losses in a power rectifier)
- AN4021 (Calculation of reverse losses in a power diode)

 $<sup>^{(1)}(</sup>dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

<sup>(2)</sup>Pulse test:  $t_p$  = 380 μs, δ < 2%

STPS2H100ZF Characteristics

## 1.1 Characteristics (curves)

0.6

0.4

0.0 0.2 0.4 0.6 0.8 1.0 1.2

Figure 1: Average forward power dissipation versus average forward current

2.0 PF(AV)(W)
1.8
1.6
1.4
1.2
1.0
0.8

1.8 2.0 2.2

1.6

100

1000

Figure 2: Average forward current versus ambient temperature ( $\delta = 0.5$ )  $I_{F(AV)}(A)$  $R_{th(j-a)} = R_{th(j-l)}$ 6 5 3 2 1 T<sub>amb</sub>(°C) 0 25 50 75 0 100 125 150 175

Figure 3: Normalized avalanche power derating versus pulse duration (T<sub>j</sub> = 125 °C)

PARM(tp)
PARM(10 µs)

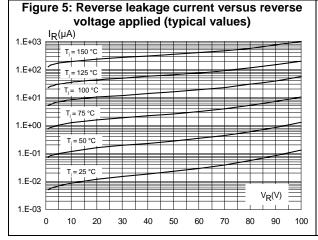
0.01

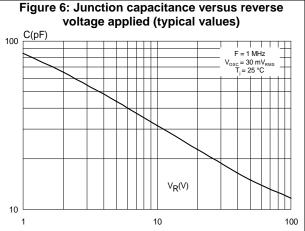
0.01

t<sub>j</sub>(µs)

10

Figure 4: Relative variation of thermal impedance junction to lead versus pulse duration  $Z_{th(j-l)}/R_{th(j-l)}$ 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 0.0 1.E-04 1.E-01 1.E+00 1.E+01





Characteristics STPS2H100ZF

Figure 7: Forward voltage drop versus forward current (typical values) 10.00 1.00 0.10 0.01 0.0 0.1 0.2 0.3 0.5 0.6 0.7 0.8 0.9 1.0

Versus copper surface under each lead (typical values)

Rth(j-a)(C/W)

200

150

Epoxy printed board FR4, e<sub>Cu</sub> = 35 μm

50

0.0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0

Figure 8: Thermal resistance junction to ambient

STPS2H100ZF Package information

## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

### 2.1 SOD123Flat package information

Figure 9: SOD123Flat package outline

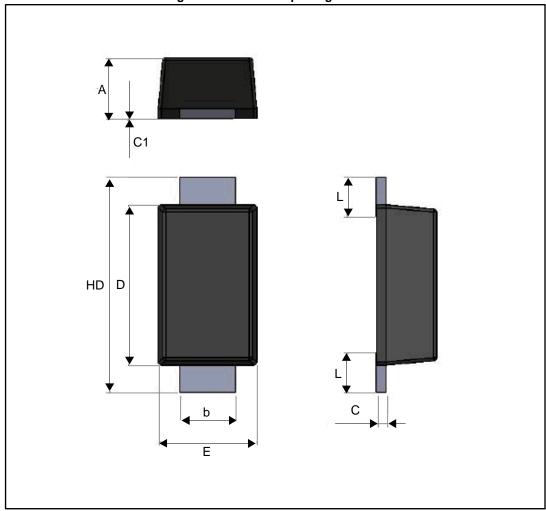
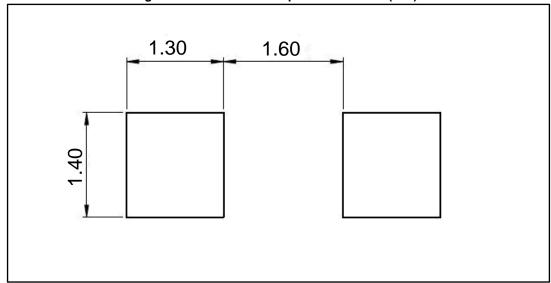


Table 5: SOD123Flat package mechanical data

	Dimensions				
Ref.	Millimeters				
	Min.	Тур.	Max.		
Α	0.86	0.98	1.10		
b	0.80	0.90	1.00		
С	0.08	0.15	0.25		
c1	0.00		0.10		
D	2.50	2.60	2.70		
Е	1.50	1.60	1.80		
HD	3.30	3.50	3.70		
L	0.45	0.65	0.85		

Figure 10: SOD123Flat footprint dimensions (mm)



STPS2H100ZF Ordering information

# 3 Ordering information

**Table 6: Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS2H100ZF	2H1	SOD123Flat	12.5 mg	3000	Tape and reel

# 4 Revision history

Table 7: Document revision history

Date	Revision	Changes
19-Aug-2016	1	Initial release.

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